

Quantum-Mechanical Modeling of the Interaction between Carbon Nanostructures and Metal Ions

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Abstract—Quantum-mechanical models for the formation of metal–carbon complexes of Co, Ni, Cu, and Zn ions with C₆₀ fullerene molecules and single-wall C₄₈ carbon nanotubes (SWCNTs) are proposed. The results of calculations show that, in aqueous solutions of electrolytes, Co, Ni, Cu, and Zn ions can be adsorbed into the C₆₀ fullerene and C₄₈ SWCNT surfaces with the formation of stable carbon-nanomaterial–metal (CNM–M) complexes; in this case, the minimum energy of the C₆₀–M complex for Co and Cu ions corresponds to the position above the C₆ cell center; for a Ni ion, above the single C–C bond in the C₆ cell; and for a Zn ion, above the C atom. The optimized states of the C₄₈–M complexes correspond to the position of metal ions above the C₆ cell center.

Keywords: metal, carbon complexes, fullerene, single-wall carbon nanotube, quantum-mechanical models, binding energy

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INTRODUCTION

In modern metal science, carbon nanomaterials are widely used especially in the role of fillers of composite materials [1, 2]. First, this is related to the unique properties of the obtained materials, because the addition of carbon nanomaterial (CNM) to a metal matrix leads to an increase in its hardness and wear and corrosion resistances [3–8]. However, if a high CNM cost price is taken into account, surface hardening is of great interest. In this case, a metal composite film with carbon nanoparticles as a filler is deposited onto the surfaces of parts. Among the variety of existing methods for obtaining metal composite films, the method of substance condensation on a substrate from vapors or solutions is now widely used; it offers the possibility of controlling metal-film formation and growth within wide limits. This process can occur using pulse currents, ultrasound, magnetic fields, and external laser radiation to intensify and stabilize the processes of metal and CNM codeposition.

The unique physical-chemical properties of electrodeposited metal films depend to a significant extent on the CNM particle concentration in the metal matrix. Therefore, the monitoring and the control of the CNM particle content in metal composite films have attracted particular attention recently. It is

impossible to solve this problem without studying the mechanism for the formation of structures of carbon-containing metal composite films. However, the process of combined metal-ion and CNM-particle codeposition onto a substrate remains studied incompletely. First, the mechanism of CNM transport from the solution volume to the substrate is not clarified. The authors of a series of papers suggested that the motion of CNM particles occurs only by a convective flux, which is produced by metal ions in the electrolyte solution [9, 10]; the assumption that CNM particles upon acquiring charge in the electrolyte solution move to the cathode under the action of an electric field generated by a potential difference between the anode and the cathode is also suggested [11, 12]. The mechanism for the formation of metal–carbon complexes can be vary greatly, and CNM particles can acquire charge by different methods.

The authors of [13, 14] theoretically considered the possibility of metal-atom adsorption into CNM particles. The binding energies of neutral atoms of transition metals with CNM (C₆₀ fullerene and C₄₈ SWCNT) particles were calculated using density functional theory. It was shown that the binding energies of atoms adsorbed into the C₆₀ and C₄₈ surfaces varied in the range of 0.05–2 eV (depending on the metal).

However, these calculations were carried out for the adsorption of neutral atoms in vacuum rather than for that of positively charged metal ions in an electrolyte solution; they cannot be used to simulate mechanisms for charge acquisition by CNM particles and for the formation of metal—carbon complexes.

To establish the mechanism of the combined codeposition of CNM particles and metal ions, we propose models of the formation of metal—carbon complexes and calculate the binding energies of Co, Ni, Cu, and Zn ions with C₆₀ fullerene and C₄₈ SWCNTs.

EXPERIMENTAL

To calculate the binding energies of metal ions with CNM particles, it is necessary to take into account the following model approximations.

First, adsorption occurs in electrolyte solutions, in particular, in aqueous solutions.

Second, to provide fulfillment of the charge-conservation law, in the calculations, it is necessary to take into account that metal ions must be adsorbed into CNM-particle surfaces, and (as a consequence) the obtained CNM—M complex must have the charge of the initial metal ion. Third, the metal-ion complex joins the CNM particle in turn; i.e., each subsequent metal ion is adsorbed into the CNM particle, which already has a charge obtained during earlier adsorption.

The binding energy of metal ions with CNM particles was calculated within the framework of density functional theory (DFT), which, recently, became one of the most popular methods for calculating the electronic structures of atoms, molecules, clusters, solid bodies, and so on [15, 16]. The growing popularity of DFT is due to, first, the combination of a rather high accuracy of the obtained results, which, in some cases, competes with that of ab initio methods for taking into account the electron correlation, and of very moderate requirements imposed on computing resources making it possible to calculate systems that consist of hundreds of atoms and are of interest for modern nanotechnology. In addition, DFT is used to study the adsorption characteristics of transition metals [17, 18], whose electrocrystallization kinetics is studied in this paper.

Numerous studies of the characteristics of molecules and clusters using DFT showed good results in the case of correct choice of the exchange-correlation functional. As shown in [19, 20], the B3LYP three-parameter hybrid functional is the most appropriate for calculations of structural and thermal-chemical characteristics of metal complexes. Using DFT, the authors of [21] studied the structure and energetics of the formation of macrocyclic complexes. It was shown that DFT using the B3LYP hybrid functional gave exact information about the structural, energy, and

kinetic characteristics. It is also known that DFT using hybrid exchange-correlation functionals makes it possible to successfully calculate the structural and electronic characteristics of complexes of transition and heavy metals with acceptable computer expenditure [22]. It was shown that when using the B3LYP functional to calculate the characteristics of the structures of transition metals, accuracy is provided on the level of ab initio methods. When optimizing the complex geometry in an aqueous solution, we also took dispersion corrections into account [23, 24]. The influence of the aqueous medium was taken into account by means of the method of a self-consistent reaction field within the framework of the model of the polarization continuum of Tomasi et al. [25].

Then the choice of the basis set of atomic orbitals used for the calculation was based on the fact that the energy and thermodynamic quantities were calculated for metals for which the interaction of valence electrons plays the largest role. The split-valence sets of basis orbitals, in particular, the 6-31g basis set or the extended 6-31-g(d) one containing *d*-type atomic orbitals for the inclusion of polarizations of the metal electron density, were used to describe such interactions.

We used the GAUSSIAN 09 program package to calculate the energies of molecules, their structures, and oscillation frequencies in the condensed state [26]. The temperature was chosen as 295 K; the pressure was 10⁵ Pa in our calculations.

CALCULATION OF THE BINDING ENERGY

To calculate the binding energy of metal ions with CNM particles, we used the density functional method, in which the energy is determined by the expression

$$W = U + T_S \{\varphi_i(r)\}_{i=1}^{N_{\text{el}}} + V_{\text{ne}}[\rho] + J[\rho] + E_{\text{xc}}[\rho], \quad (1)$$

where U is the potential energy of the interaction of nuclei, T_S is the electron kinetic energy, V_{ne} is the energy of attraction of electrons to nuclei, J is the classical contribution of the interelectron repulsion to the energy, and E_{xc} is the exchange-correlation functional including the static electron correlation.

The binding energy (ΔW) of an adsorbed metal ion with a CNM particle was defined as the difference between the total energy of the CNM complex with the adsorbed metal ion ($W_{\text{C+M}}$) and the sum of energies of its components ($W_{\text{C}}, W_{\text{M}}$)

$$\Delta W = |W_{\text{C+M}} - (W_{\text{C}} + W_{\text{M}})|, \quad (2)$$

where W_{C} is the CNM-particle energy and W_{M} is the metal-ion energy.

In the case of the by-turn adsorption of metal ions into the CNM surface, the binding energy was calcu-

Table 1. Results of optimizing the distance from Co, Ni, Cu, and Zn ions to the C₆₀ fullerene and C₄₈ SWCNT surfaces

		$d, \text{Å}$			
		Co	Ni	Cu	Zn
C ₆₀ fullerene	Water	1.991	1.349	1.865	2.123
	Vacuum			1.910 [14]	
C ₄₈ SWCNT	Water	1.631	1.427	1.564	2.062
	Vacuum	2.028 [13]	2.020 [13]	2.238 [13]	

lated as the difference between the total energy of the CNM complex with respect to one (W_{C+M}), two (W_{C+2M}), and three (W_{C+3M}) adsorbed metal ions and the energy of components: the CNM-particle energy (W_C) and the energy of one metal ion (W_M)

$$\Delta W_1 = |W_{C+M} - (W_C + W_M)|, \quad (3)$$

the energy of the CNM particle with one adsorbed metal ion (W_{C+M}) and that of one metal ion (W_M)

$$\Delta W_2 = |W_{C+2M} - (W_{C+M} + W_M)|, \quad (4)$$

the energy of the CNM particle with two adsorbed metal ions (W_{C+2M}) and that of one metal ion (W_M)

$$\Delta W_3 = |W_{C+3M} - (W_{C+2M} + W_M)|. \quad (5)$$

The geometry of the charged complex that consisted of a CNM and an adsorbed metal ion was optimized. The equilibrium geometry of the C₆₀-M and C₄₈-M complexes is shown in Fig. 1. C₄₈ SWCNT dangling bonds were closed by H atoms to decrease the influence of boundary effects (Fig. 1b).

Table 1 contains our obtained results of optimizing the distance from adsorbed metal ions to the CNM particle surface (d) for an aqueous medium and the calculated results in [13, 14] for vacuum. In our calculations, the quantity d determines either the length of the perpendicular from the ion to the plane of the C₆ or C₅ structure ring in the case of the adsorption of ions into the C₆₀ fullerene surface or that of the perpendicular from the ion to the plane of lower four carbon atoms in the C₆ cell in the case of ion adsorption into the C₄₈ SWCNT surface.

It was shown that, in the case of copper and cobalt ions, C₆₀-M complexes with the minimum energy corresponded to the structure where the ion is above the C₆ cell center. The Ni-ion position above the middle of the C-C bond turned out to be minimum for the C₆₀-Ni complex, while, for the C₆₀-Zn complex, the structure in which the ion is above the C atom was most stable. Similarly, the optimized states of the C₄₈-M complexes corresponded to the metal-ion position above the C₆ cell center. The tendency toward an

increase in the optimized distance in the series Ni < Cu < Co < Zn was observed for both C₆₀ and C₄₈.

Because the adsorption of one metal ion or more into the CNM-particle surface is theoretically possible, we took into account models in which one nanoparticle can form bonds with at most three metal ions. Taking into account that the system charge must increase by $2e$ (e is the elementary electric charge) in the case of the addition of each new metal ion, we proposed and optimized models of complexes with one, two or three bound metal ions, which had charges of $+2e$, $+4e$, and $+6e$, respectively.

Table 2 contains the results of optimizing the distance between the adsorbed Ni ion and the C₆₀ fullerene surface for different complex charges; they were calculated for interaction in vacuum and water. As our calculations showed (Table 2), the distance between the adsorbed metal ion and the CNM-particle surface increases with increasing charge.

Table 3 contains the results of calculating the binding energy (ΔW) of an adsorbed metal ion with a CNM particle. It is seen from Table 3 that all considered metal ions form strong bonds with C₄₈ particles, unlike the compounds with C₆₀, because their binding energy exceeds a thermal-motion energy of 0.025 eV significantly.

In the case of the subsequent attachment of several metal ions to one CNM particle, their binding energy decreases, as is seen from the calculated results for the C₆₀ fullerene and the Ni ion given in Table 4. Optimization of the geometry of C₆₀ complexes with several Ni ions led to the following results: four ions were arranged in the form of a square with a fullerene at the

Table 2. Distance between the adsorbed Ni ion and the C₆₀ fullerene surface for different complex charges

q		$+2e$	$+4e$	$+6e$
$d, \text{Å}$	Vacuum	1.869	1.881	1.999
	Water	0.987	1.392	1.410

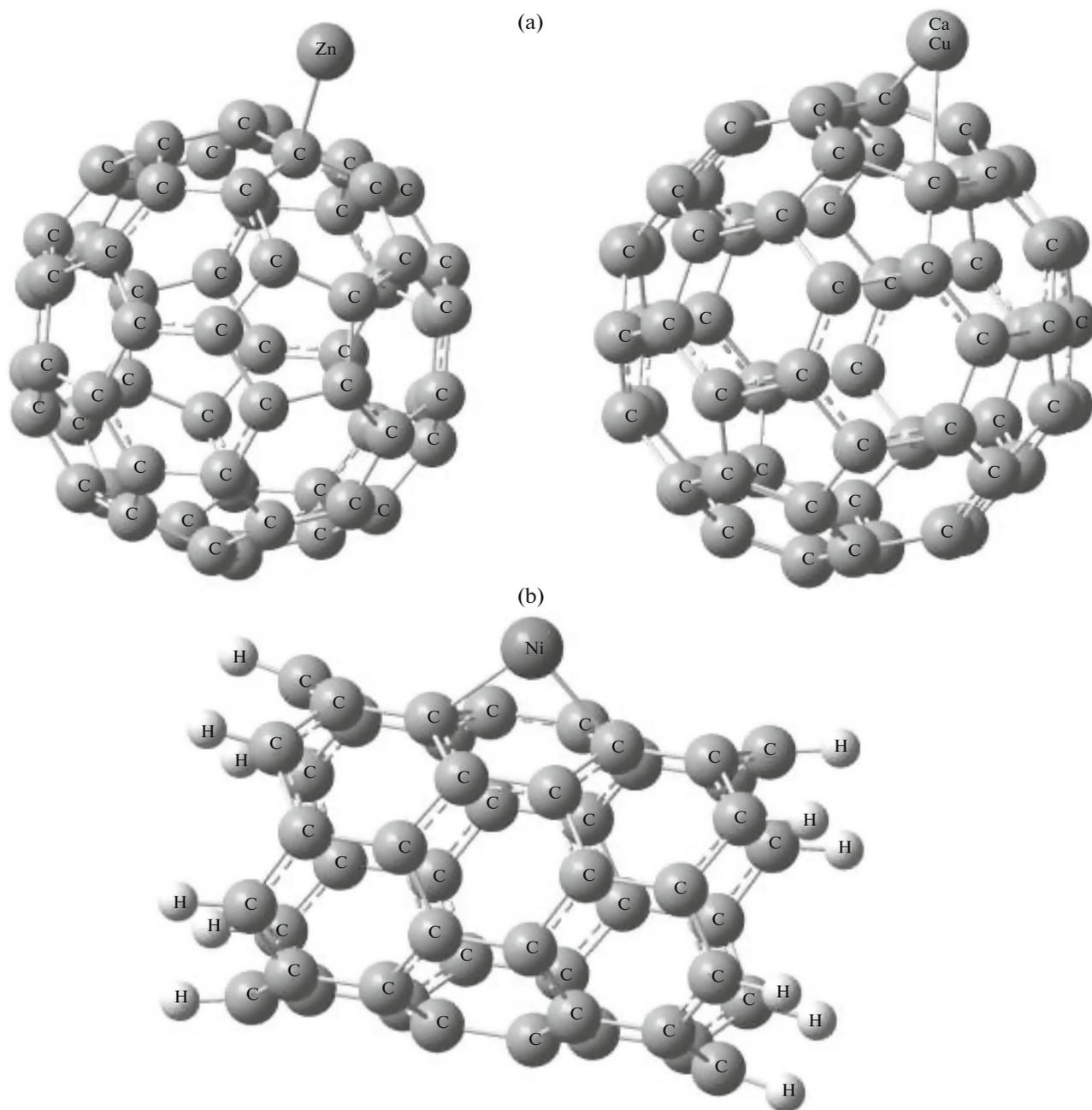


Fig. 1. Arrangement of the metal ion adsorbed into the (a) C₆₀ fullerene and (b) C₄₈ SWCNT surfaces.

center, three ions acquired the form of a rectangular isosceles triangle, and two ions were located along the fullerene diameter. In all cases, the ions were located above the single C–C bond. The interaction of CNM particles with two or more metal ions did not lead to the formation of stable complexes (Table 4), and all further calculations were carried out for a charge of $+2e$, which corresponded to the valence of one metal ion.

Comparison of the obtained binding energies of the CNM–M complex with the thermal-motion energy showed that, in aqueous solutions of electrolytes, Co, Ni, Cu, Zn ions can be adsorbed into the C₆₀ fullerene and C₄₈ SWCNT surfaces with the formation of stable CNM–M complexes. Consequently, CNM particles can be transported from the volume of the aqueous solution of the electrolyte to the cathode surface,

Table 3. Binding energy of Co, Ni, Cu, and Zn ions with CNM particles

	ΔW , eV			
	Co	Ni	Cu	Zn
C ₆₀ fullerene	1.406	1.907	2.933	0.026
C ₄₈ SWCNT	2.005	2.234	3.158	0.533

Table 4. The binding energy of the C₆₀–Ni complex as a function of the number of adsorbed Ni ions

	Number of adsorbed ions		
	1	2	3
ΔW , eV	1.907	1.582	0.240

because the CNM–M complex acquires positive charge.

CONCLUSIONS

Our proposed mechanism for the adsorption of metal ions into the CNM particle surface with the further motion of the charged complex in the cathode direction was verified using the computing method. Comparison of the results of calculating the binding energies of the CNM–M complexes with the thermal-motion energies showed that, in an aqueous solution of electrolytes, Co, Ni, Cu, and Zn ions can be adsorbed into the C₆₀ fullerene and C₄₈ SWCNT surfaces with the formation of stable CNM–M complexes. For the C₆₀–M and C₄₈–M complexes, the binding energies increased in the Zn < Co < Ni < Cu sequence. It was shown that complexes adsorbed by one metal ion or more were not stable.

Thus, the transport of CNM particles from the solution volume to the cathode can occur via the stage of the adsorption of deposited-material cations into their surfaces. The metal–carbon complex that acquired the charge is transported to the cathode, where, during the deposition process, it turns out to be surrounded by discharged metal ions.

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